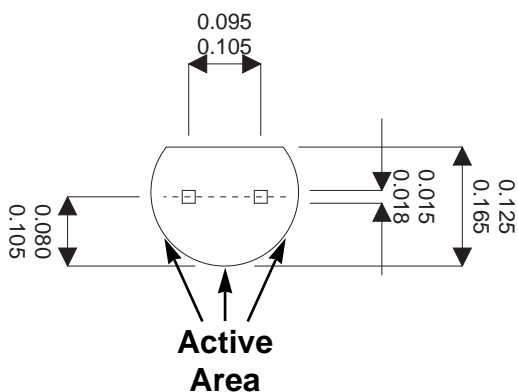
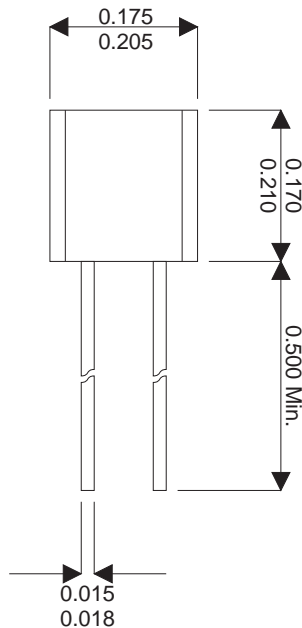


MECHANICAL DATA

Dimensions in inches.



TO-92 Package

P.I.N. PHOTODIODE



FEATURES

- WATER CLEAR PLASTIC
- WIDE SPECTRAL RESPONSE
- 0.1" (2.54mm) LEAD SPACING
- LOW DARK CURRENT
- SUITABLE FOR REMOTE CONTROL
- HIGH SENSITIVITY

DESCRIPTION

The SMP550G-X2 is a silicon PIN photodiode which is incorporated in a colourless plastic package. The terminals are solder tabs with 0.1" (2.54mm) spacing. Due to its design the diode can be assembled vertically on PC board.

Arrays can be realised by multiple arrangements. This versatile photo detector can be used as a diode as well as a voltage cell.

The PIN photodiode is outstanding for low junction capacitance, high cut off frequency and short switching time. It is particularly suitable for IR sound transmission and remote control.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

Operating temperature range	-40°C to +70°C
Storage temperature range	-45°C to +80°C
Temperature coefficient of responsivity	0.35% per °C
Temperature coefficient of dark current	x2 per 8°C rise
Reverse Breakdown Voltage	60V

CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise stated)

Characteristic	Test Conditions.	Min.	Typ.	Max.	Units
Responsivity	λ at 900nm	0.45	0.55		A/W
Active Area			5.19		mm ²
Dark Current	E = 0 Dark 1V Reverse		0.25	2	nA
	E = 0 Dark 10V Reverse		1	5	
Breakdown Voltage	E = 0 Dark 10 μ A Reverse	60	80		V
Capacitance	E = 0 Dark 0V Reverse		30	55	pF
	E = 0 Dark 20V Reverse		5	10	
Rise Time	30V Reverse 50 Ω		8		ns
NEP	900nm		9.8		W/ $\sqrt{\text{Hz}}$

